

Preferred Device

Surface Mount Schottky Power Rectifier

The MBRS540T3 employs the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes in surface mount applications where compact size and weight are critical to the system.

Features

- Pb–Free Package is Available
- Small Compact Surface Mountable Package with J-Bend Leads
- Rectangular Package for Automated Handling
- Highly Stable Oxide Passivated Junction
- Excellent Ability to Withstand Reverse Avalanche Energy Transients
- Guardring for Stress Protection

Mechanical Characteristics

- Case: Epoxy, Molded, Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 217 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Polarity: Notch in Plastic Body Indicates Cathode Lead
- ESD Rating: Machine Model, C (> 400 V) Human Body Model, 3B (> 8000 V)
- Device Meets MSL 1 Requirements

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--|--|-------------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | 40 | V |
| Average Rectified Forward Current (At Rated V_R , $T_C = 105^{\circ}C$) | I _{F(AV)} | 5 | A |
| Peak Repetitive Forward Current (At Rated V _R , Square Wave, 20 KHz, T _C = 80°C) | I _{FRM} | 10 | A |
| Non–Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz) | I _{FSM} | 190 | A |
| Storage Temperature Range | Tstg | -65 to +150 | °C |
| Operating Junction Temperature | ТJ | -65 to +125 | °C |
| Voltage Rate of Change (Rated V_R) | dv/dt | 10,000 | V/µs |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



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SCHOTTKY BARRIER RECTIFIER 5.0 AMPERES 40 VOLTS

MARKING DIAGRAM





ORDERING INFORMATION

| Device | Package | Shipping [†] |
|------------|------------------|-----------------------|
| MBRS540T3 | SMC | 2500/Tape & Reel |
| MBRS540T3G | SMC (Pb-Free) | 2500/Tape & Reel |

⁺For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

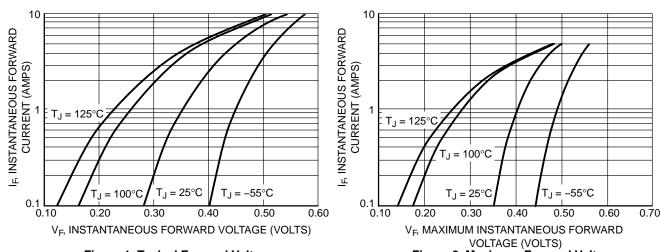
Preferred devices are recommended choices for future use and best overall value.

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| Characteris | tic | Symbol | Value | Unit |
|---|---|---|-----------|------|
| Thermal Resistance – Junction–to–Lead (Note 1) Thermal Resistance – Junction–to–Ambient (Note 1) | | $R_{	extsf{	heta}JL}$ $R_{	extsf{	heta}JA}$ | 12 111 | °C/W |
| ELECTRICAL CHARACTERISTICS | | · | | • |
| Maximum Instantaneous Forward Voltage (Note 2) | (i _F = 5.0 A, T _C = 25°C) | V _F | 0.50 | V |
| Maximum Instantaneous Reverse Current (Note 2) | (Rated dc Voltage, $T_C = 25^{\circ}C$) (Rated dc Voltage, $T_C = 100^{\circ}C$) | i _R | 0.3 15 | mA |

1. Rating applies when surface mounted on the minimum pad size recommended.

2. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.



TYPICAL CHARACTERISTICS



Figure 2. Maximum Forward Voltage

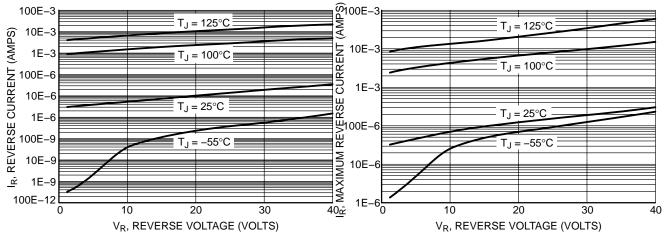
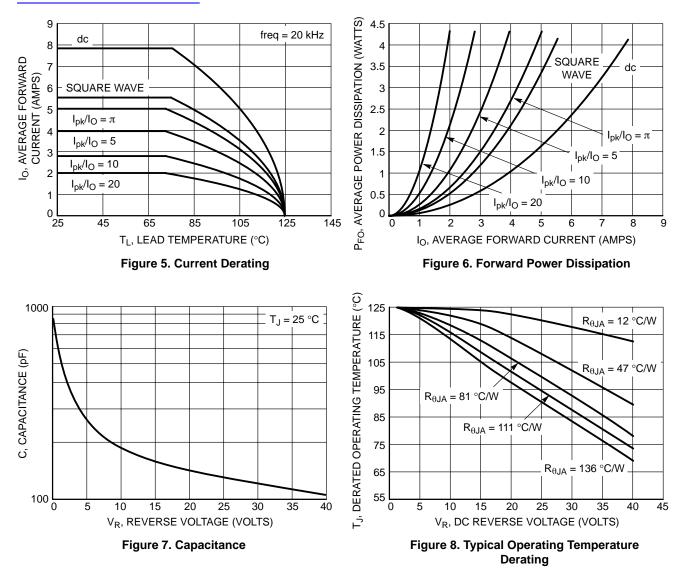




Figure 4. Maximum Reverse Current

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TYPICAL CHARACTERISTICS



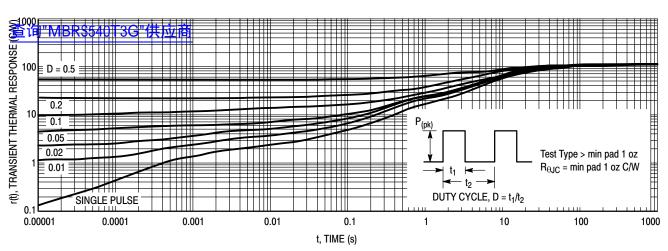


Figure 9. Thermal Response – MBRS540T3 on min pad

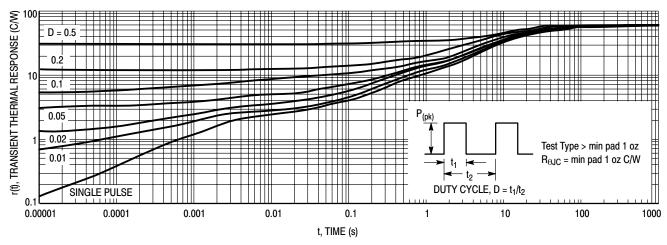
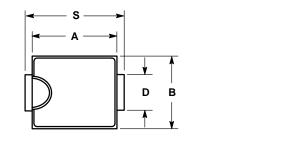


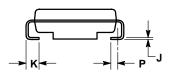
Figure 10. Thermal Response – MBRS540T3 on 1" pad

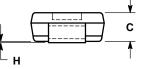
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PACKAGE DIMENSIONS

SMC CASE 403-03 ISSUE D



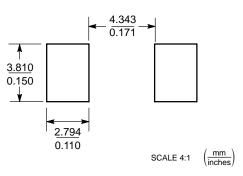




NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. D DIMENSION SHALL BE MEASURED WITHIN DIMENSION P.
4. 403-01 THRU -02 OBSOLETE, NEW STANDARD 403-03.

| | INCHES | | MILLIMETERS | |
|-----|-----------|--------|-------------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.260 | 0.280 | 6.60 | 7.11 |
| В | 0.220 | 0.240 | 5.59 | 6.10 |
| С | 0.075 | 0.095 | 1.90 | 2.41 |
| D | 0.115 | 0.121 | 2.92 | 3.07 |
| Н | 0.0020 | 0.0060 | 0.051 | 0.152 |
| J | 0.006 | 0.012 | 0.15 | 0.30 |
| Κ | 0.030 | 0.050 | 0.76 | 1.27 |
| Р | 0.020 REF | | 0.51 | REF |
| S | 0.305 | 0.320 | 7.75 | 8.13 |

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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